
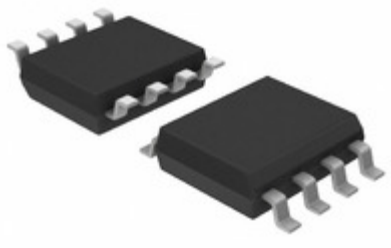

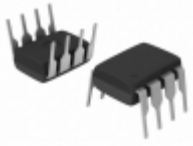

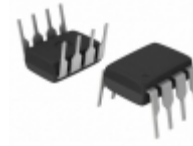
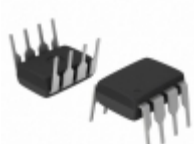
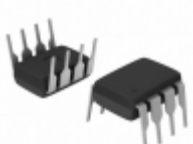


 <p>ADVANCED LINEAR DEVICES, INC.</p>	<h2>ALD212900SAL</h2>
	<p>Hersteller-Teilenummer: ALD212900SAL</p> <p>Hersteller / Marke: Advanced Linear Devices, Inc.</p> <p>Teil der Beschreibung: MOSFET 2N-CH 10.6V 0.08A 8SOIC</p> <p>Datenblätter:  ALD212900SAL.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	ALD212900SAL
Hersteller	Advanced Linear Devices, Inc.
Beschreibung	MOSFET 2N-CH 10.6V 0.08A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	20mV @ 20µA
Supplier Device-Gehäuse	8-SOIC
Serie	EPAD®, Zero Threshold™
Rds On (Max) @ Id, Vgs	14 Ohm
Leistung - max	500mW
Verpackung	Tube
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Betriebstemperatur	0°C ~ 70°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	30pF @ 5V
Gate Charge (Qg) (Max) @ Vgs	-
Typ FET	2 N-Channel (Dual) Matched Pair
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	10.6V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	80mA

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Sie können auch interessiert

<p>sein:</p>  <p>ALD212620DNUW IDEC 30MM PB MOM 120V TR 2NO WHT</p>	 <p>ALD212902PAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8DIP</p>	 <p>ALD212620DNUY IDEC 30MM PB MOM 120V TR 2NO YEL</p>	 <p>ALD212900APAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8DIP</p>
 <p>ALD212908APAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8DIP</p>	 <p>ALD212900PAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8DIP</p>	 <p>ALD212900ASAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8SOIC</p>	 <p>ALD212904SAL Advanced Linear Devices Inc. MOSFET 2N-CH 10.6V 0.08A 8SOIC</p>

Verwandtes Hot-Keyword

Mehr

ALD212900SAL Advanced Linear Devices, Inc.	ALD212900SAL Datenblatt	ALD212900SAL-Datenblätter	ALD212900SAL PDF	Advanced Linear Devices, Inc. ALD212900SAL
ALD212900SAL Electronic	ALD212900SAL-Komponenten	ALD212900SAL-Verteiler	ALD212900SAL-Bild	ALD212900SAL-Teil
ALD212900SAL Preis	ALD212900SAL Hersteller	ALD212900SAL Bild	ALD212900SAL Aktie	ALD212900SAL Inventar
ALD212900SAL Neu	ALD212900SAL Original	ALD212900SAL garantiert	ALD212900SAL RFQ	ALD212900SAL Online bestellen

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